

10-000903 is 10-000901 with an extended lid

Switched Attenuator 0.25W, 0 - 15dB (10-000901)

In many practical applications for Cell Enhancers etc., the gain in each path is found to be excessive. Therefore, provision is made within the unit for the setting of attenuation in each path, to reduce the gain.

10-000901 provides attenuation from 0 - 15dB in 2 dB steps The attenuation is simply set using the four miniature toggle switches on the top of each unit. Each switch is clearly marked with the attenuation it provides, and the total attenuation in line is the sum of the values switched in. They are designed to maintain an accurate 50Ω impedance over their operating frequency at both input and output.

10-000901 Specification

PARAMETER		SPECIFICATION
Attenuation Values:		0-15dB
Attenuation Steps:		1, 2, 4 and 8dB
Power Handling:		0.25 Watt
Attenuation Accuracy:		± 1.0 dB
Frequency Range		DC to 1GHz
Impedance:		50Ω
Connectors:		SMA
VSWR:		1.3:1
Weight		0.2kg
Temperature range:	operation:	-20°C to +60°C
	storage:	-40°C to +70°C

Switched Attenuator 0.25W, 0 - 15dB (10-000903)

In many practical applications for Cell Enhancers etc., the gain in each path is found to be excessive. Therefore, provision is made within the unit for the setting of attenuation in each path, to reduce the gain.

10-0009903 provides attenuation from 0 - 15dB in 2 dB steps The attenuation is simply set using the four miniature toggle switches on the top of each unit. Each switch is clearly marked with the attenuation it provides, and the total attenuation in line is the sum of the values switched in. They are designed to maintain an accurate 50Ω impedance over their operating frequency at both input and output.

10-000903 Specification

PARAMETER		SPECIFICATION
Attenuation Values:		0-15dB
Attenuation Steps:		1, 2, 4 and 8dB
Power Handling:		0.25 Watt
Attenuation Accuracy:		± 1.0 dB
Frequency Range		DC to 1GHz
Impedance:		50Ω
Connectors:		SMA
VSWR:		1.3:1
Weight		0.2kg
Temperature range:	operation:	-20°C to +60°C
	storage:	-40°C to +70°C

17-001117, Det. & 17-001201, Atten. Automatic Gain Control

Description

The equipment is fitted with an Automatic Gain Control (AGC) system. This is generally fitted in the Uplink path (not usually needed in the downlink path, as the signal here is at an almost constant level), to avoid overloading the amplifiers (with the associated performance degradation) should a mobile be operated very close to the unit.

Normally the attenuator is at minimum attenuation. The detector/amplifier unit monitors the RF level being delivered by the power amplifier, and when a certain threshold is reached it begins to increase the value of the attenuator to limit the RF output to the (factory set) threshold. Therefore overloading of the power amplifier is avoided.

The factory set threshold is 1dB below the Enhancer 1dB compression point. Some adjustment of this AGC threshold level is possible, a 10dB range is mostly achieved. It is not recommended under any circumstances to adjust the AGC threshold to a level greater than the 1dB compression point as system degradation will occur.

The detector comprises of a 50Ω transmission line with a resistive tap which samples a small portion of the mainline power. The sampled signal is amplified and fed to a conventional half wave diode rectifier, the output of which is a DC voltage proportional to the RF input signal.

This DC voltage is passed via an inverting DC amplifier with integrating characteristics, to the output, which drives the attenuation control line of the corresponding AGC attenuator. This unit is fitted at some earlier point in the RF circuit.

For small signals, below AGC onset, the output control line will be close to 12V and the AGC attenuator will have minimum attenuation. As the signal level increases the control line voltage will fall, increasing the attenuator value and keeping the system output level at a constant value.

The AGC onset level is adjusted by the choice of sampler resistor R1 and by the setting of potentiometer VR1.

The attenuator comprises a 50Ω P.I.N diode, voltage-variable attenuator with a range of 3 to 30dB. The attenuation is controlled by a DC voltage which is derived from the associated AGC detector unit.

Technical Specification

PARAMETER		SPECIFICATION
Frequency range:		up to 1000MHz
Attenuation range:		3 to 30dB
Attenuation steps:		continuously variable
VSWR:		better than 1.2:1
RF Connectors:		SMA female
Power handling:	attenuator:	1W
	detector/amp:	>30W (or as required)
Temperature range:	operation:	-10°C to +60°C
	storage:	-20°C to +70°C
Size:	attenuator pcb	50 x 42 x 21mm
	detector/amp pcb	54 x 42 x 21mm
Weight:	attenuator:	90grams
	detector/amp:	100grams

AGC Attenuator Module (17-001201)

The AFL Automatic Gain Control system consists of two units, a detector/amplifier and an attenuator. The detector/amplifier unit is inserted in the RF path on the output of the power amplifier, and the attenuator is situated in the RF path between the 1st and 2nd stages of amplification. However, in this case only the attenuator is employed as part of the simplex control system.

The attenuator comprises a 50Ω P.I.N diode, voltage-variable attenuator with a range of 3 to 30dB. The attenuation is controlled by a DC voltage which is derived in this instance from the associated Simplex controller board.

Low Power Amplifier (12-021901)

The low power amplifier used is a triple stage solid-state low-noise amplifier. Class A circuitry is used in the unit to ensure excellent linearity over a very wide dynamic range. The three active devices are very moderately rated to provide a long trouble-free working life.

Its housing is an aluminium case (Iridite NCP finish) with SMA connectors for the RF input/output and a D-Type connector for the power supply and the Current Fault Alarm Function. There are no adjustments on this amplifier, and in the unlikely event of failure then the entire amplifier should be replaced.

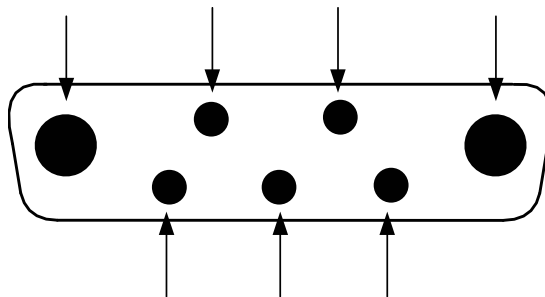
12-021901 Specification

PARAMETER		SPECIFICATION
Frequency range		800-960MHz*
Bandwidth		20MHz *
Maximum RF output		>1.0 Watt
Gain		15dB
1dB compression point		+30.5dBm
3 rd order intercept point		+43dBm
Noise Figure		<6dB
VSWR		better than 1.5:1
Connectors		SMA female
Supply		500mA @ 10-15V DC
Temperature range	operational	-10°C to +60°C
	storage	-20°C to +70°C
Weight		0.5 kg
Size		167x52x25mm

* Tuned to Customer's specification

Low Power Amplifier (12-021901) 7-Way Connector Pin-outs

7-Way Connector Pin-out details	
Connector Pin	Signal
A1 (large pin)	+24V DC
A2 (large pin)	GND
1	Alarm relay common
2	TTL alarm/0V good
3	Alarm relay contact (bad)
4	Alarm relay contact (good)
5	O/C good/0V bad (TTL)



12-018001

10W 800MHz Power Amplifier

Description

This amplifier is a Class A 10W power amplifier from 800-960MHz in a 1 stage balanced configuration. It demonstrates a very high linearity and a very good input/output return loss (RL). It has built in a Current Fault Alarm Function.

Its housing is an aluminium case (Alocrom 1200 finish) with SMA connectors for the RF input/output and a D-Type connector for the power supply and the Current Fault Alarm Function.

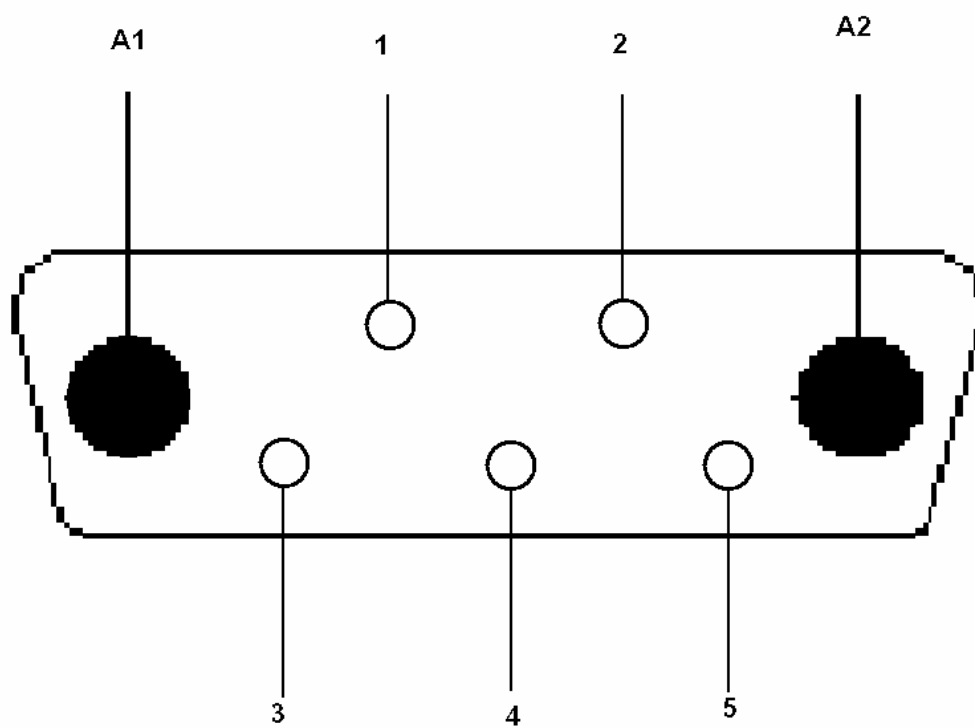
Technical Specification

PARAMETER		SPECIFICATION
Frequency range:		800-960MHz
Small signal gain:		30dB
Gain flatness:		±1.2dB
I/O Return loss:		>18dB
1dB compression point:		40.4dBm
OIP3:		54dBm
Supply voltage:		10-24V DC
Supply current:		3.5Amps @12V(typical)
Temperature range	operational:	-10°C to +60°C
	storage:	-20°C to +70°C
Weight:		<2kg (no heatsink)

PA 7-Way Connector Pin-outs

Connector Pin	Signal
A1 (large pin)	+10-24V DC
A2 (large pin)	GND
1	Alarm relay common
2	TTL alarm/0V good
3	Alarm relay contact (bad)
4	Alarm relay contact (good)
5	O/C good/0V bad (TTL)

7-Way Connector Graphical Representation



Description

The Gallium-Arsenide low noise amplifiers used in the unit are double stage, solid-state low noise amplifiers. Class A circuitry is used throughout the units to ensure excellent linearity and extremely low noise over a very wide dynamic range. The active devices are very moderately rated to provide a long trouble-free working life. There are no adjustments on these amplifiers, and in the unlikely event of a failure, then the complete amplifier should be replaced. This amplifier features its own in-built alarm system which gives a volt-free relay contact type alarm that is easily integrated into the main alarm system.

Technical Specification 11-006702

PARAMETER		SPECIFICATION
Frequency range:		800 – 1000MHz
Bandwidth:		<200MHz
Gain:		29dB (typical)
1dB Compression point:		20dBm
OIP3:		33dBm
Input/Output return loss:		>18dB
Noise figure:		1.3dB (typical)
Power consumption:		180mA @ 24V DC
Supply voltage:		10-24V DC
Connectors:		SMA female
Temperature range:	operational:	-10°C to +60°C
	storage:	-20°C to +70°C
Size:		90 x 55 x 30.2mm
Weight:		290gms (approximately)

LNA 'D' Connector Pin-out details

Connector pin	Signal
1	+Ve input (10-24V)
2	GND
3	Alarm Relay O/P bad
4	Alarm Relay common
5	Alarm Relay good
6	No connection
7	TTL voltage set
8	TTL alarm/0V (good)
9	O/C good/0V bad

Description

The equipment is fitted with a wide dynamic range Automatic Gain Control (AGC) system. This is generally fitted in the Uplink path (not usually needed in the downlink path, as the signal here is at an almost constant level), to avoid overloading the amplifiers (with the associated performance degradation) should a mobile be operated very close to the unit.

The AFL wide dynamic range Automatic Gain Control system consists of two units, a detector/amplifier and an attenuator. The detector/amplifier unit is inserted in the RF path on the output of the power amplifier, and the attenuator is situated in the RF path between the 1st and 2nd stages of amplification.

Normally the attenuator is at minimum attenuation. The detector/amplifier unit monitors the RF level being delivered by the power amplifier, and when a certain threshold is reached it begins to increase the value of the attenuator to limit the RF output to the (factory set) threshold. Therefore overloading of the power amplifier is avoided.

The factory set threshold is 1dB below the Enhancer 1dB compression point. Some adjustment of this AGC threshold level is possible, a 10dB range is mostly achieved. It is not recommended under any circumstances to adjust the AGC threshold to a level greater than the 1dB compression point as system degradation will occur.

The detector comprises of a 50Ω transmission line with a resistive tap which samples a small portion of the mainline power. The sampled signal is amplified and fed to a conventional half wave diode rectifier, the output of which is a DC voltage proportional to the RF input signal.

This DC voltage is passed via an inverting DC amplifier with integrating characteristics, to the output, which drives the attenuation control line of the corresponding AGC attenuator. This unit is fitted at some earlier point in the RF circuit.

The unit contains a 12V DC regulator in the detector module, which supplies stabilised voltage to the DC amplifier and via an external cableform to the AGC attenuator.

For small signals, below AGC onset, the output control line will be close to 12V and the AGC attenuator will have minimum attenuation. As the signal level increases the control line voltage will fall, increasing the attenuator value and keeping the system output level at a constant value. The AGC onset level is adjusted by the choice of sampler resistor R1 and by the setting of potentiometer VR1, (factory set @ time of system test) do not adjust unless able to monitor subsequent RF levels.

The attenuator comprises a 50Ω P.I.N diode, voltage-variable attenuator with a range of 3 to 30dB. The attenuation is controlled by a DC voltage which is derived from the associated AGC detector unit.

Technical Specification

PARAMETER		SPECIFICATION
Frequency range:		up to 1000MHz
Attenuation range:		3 to 30dB
Attenuation steps:		continuously variable
VSWR:		better than 1.2:1
RF Connectors:		SMA female
Power handling:	attenuator:	1W
	detector/amp:	>30W (or as required)
Temperature range:	operation:	-10°C to +60°C
	storage:	-20°C to +70°C
Size:	attenuator (pcb)	50 x 42 x 21mm
	Detector (pcb)	54 x 42 x 21mm
Weight:	attenuator:	90grams
	detector/amp:	100grams